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- 2-V to 5.5-V V<sub>CC</sub> Operation
- Max t<sub>pd</sub> of 8 ns at 5 V
- Typical  $V_{OLP}$  (Output Ground Bounce) <0.8 V at  $V_{CC}$  = 3.3 V,  $T_A$  = 25°C
- Typical V<sub>OHV</sub> (Output V<sub>OH</sub> Undershoot) >2.3 V at V<sub>CC</sub> = 3.3 V , T<sub>A</sub> = 25°C
- Support Mixed-Mode Voltage Operation on All Ports
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
   2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

SN54LV573A . . . J OR W PACKAGE SN74LV573A ... RGY PACKAGE SN54LV573A ... FK PACKAGE SN74LV573A ... DB, DGV, DW, NS, (TOP VIEW) (TOP VIEW) **OR PW PACKAGE** ₽₩°°°ã 202 (TOP VIEW) Ш 20 🛛 V<sub>CC</sub> OE [ 1 20 3 2 1 20 19 3D 18 2Q 4 1D 2 19 1Q 1D 2 19 1Q 4D 17 3Q 5 2D Πз 18 🛛 2Q 2D 3 18 2Q 5D 16 4Q 3D 6 3D 17 🛛 3Q 4 17 3Q 4 6D Π7 15 5Q 4D 4D 5 16 4Q 5 16 🛛 4Q 7D 14 6Q 8 | 5D 6 15 5Q 5D 6 15 🛛 5Q 9 10 11 12 13 6Q 6D 7 14 6D Π7 14 🛛 6Q 7D 8 13 7Q DND DNE Щãã 7D П 8 13 7Q 12 8Q 8D 9 12 8Q 8D 9 GND 10 11 🛛 LE 10 11 Щ GND

#### description/ordering information

T <sub>A</sub>	РАСКА	GE†	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	QFN – RGY	Reel of 1000	SN74LV573ARGYR	LV573A
		Tube of 25	SN74LV573ADW	11/5704
10°C to 95°C	SOIC – DW	Reel of 2000	SN74LV573ADWR	LV573A
	SOP – NS	Reel of 2000	SN74LV573ANSR	74LV573A
	SSOP – DB Reel of 2000		SN74LV573ADBR	LV573A
–40°C to 85°C		Tube of 70	SN74LV573APW	
	TSSOP – PW	Reel of 2000	SN74LV573APWR	LV573A
		Reel of 250	SN74LV573APWT	
	TVSOP – DGV	Reel of 2000	SN74LV573ADGVR	LV573A
	VFBGA – GQN	Reel of 1000	SN74LV573AGQNR	LV573A
	CDIP – J	Tube of 20	SNJ54LV573AJ	SNJ54LV573AJ
–55°C to 125°C	CFP – W	Tube of 85	SNJ54LV573AW	SNJ54LV573AW
	LCCC – FK	Tube of 55	SNJ54LV573AFK	SNJ54LV573AFK

#### **ORDERING INFORMATION**

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



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#### SN54LV573A, SN74LV573A OCTAL TRANSPARENT D-TYPE LATCHES WITH 3-STATE OUTPUTS SCLS4111 – APRIL 1998 – REVISED APRIL 2005

#### description/ordering information (continued)

The 'LV573A devices are octal transparent D-type latches designed for 2-V to 5.5-V V<sub>CC</sub> operation.

These devices feature 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. This device is particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

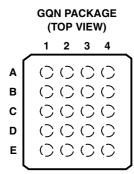
While the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is taken low, the Q outputs are latched at the logic levels set up at the D inputs.

A buffered output-enable ( $\overline{OE}$ ) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without need for interface or pullup components.

OE does not affect the internal operations of the latches. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to V<sub>CC</sub> through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.



#### terminal assignments

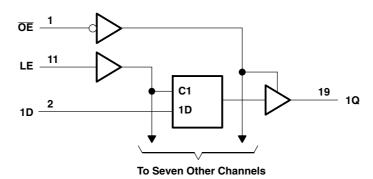
	1	2	3	4
Α	1D	OE	V <sub>CC</sub>	1Q
в	3D	3Q	2D	2Q
С	5D	4D	5Q	4Q
D	7D	7Q	6D	6Q
Е	GND	8D	LE	8Q

## FUNCTION TABLE

	(cuo		
	INPUTS	OUTPUT	
OE	LE	Q	
L	Н	Н	Н
L	н	L	L
L	L	Х	Q <sub>0</sub>
Н	Х	Х	Z



#### logic diagram (positive logic)



Pin numbers shown are for the DB, DGV, DW, FK, J, NS, PW, RGY, and W packages.

#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V <sub>CC</sub>
or power-off state, V <sub>O</sub> (see Note 1) –0.5 V to 7 V
Output voltage range applied in the high or low state, $V_O$ (see Notes 1 and 2)0.5 V to $V_{CC}$ + 0.5 V
Input clamp current, I <sub>IK</sub> (V <sub>I</sub> < 0)
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0)
Continuous output current, $I_O$ (V <sub>O</sub> = 0 to V <sub>CC</sub> ) ±35 mA
Continuous current through V <sub>CC</sub> or GND ±70 mA
Package thermal impedance, $\theta_{JA}$ (see Note 3): DB package
(see Note 3): DGV package
(see Note 3): DW package
(see Note 3): GQN package
(see Note 3): NS package
(see Note 3): PW package
(see Note 4): RGY package
Storage temperature range, T <sub>stg</sub>

† Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

2. This value is limited to 5.5 V maximum.

3. The package thermal impedance is calculated in accordance with JESD 51-7.

4. The package thermal impedance is calculated in accordance with JESD 51-5.



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#### recommended operating conditions (see Note 5)

			SN54L	V573A	SN74L	/573A	
			MIN	MAX	MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		2	5.5	2	5.5	V
		$V_{CC} = 2 V$	1.5		1.5		
.,		$V_{CC}$ = 2.3 V to 2.7 V	$V_{CC}  imes 0.7$		$V_{CC}  imes 0.7$		.,
VIH	High-level input voltage	$V_{CC}$ = 3 V to 3.6 V	$V_{CC} \times 0.7$		$V_{CC}  imes 0.7$		v
		$V_{CC}$ = 4.5 V to 5.5 V	$V_{CC} \times 0.7$		$V_{CC}  imes 0.7$		
		$V_{CC} = 2 V$		0.5		0.5	
		$V_{CC}$ = 2.3 V to 2.7 V		$V_{CC}  imes 0.3$		$V_{CC}  imes 0.3$	.,
V <sub>IL</sub>	Low-level input voltage	$V_{CC}$ = 3 V to 3.6 V		$V_{CC}\!\times\!0.3$		$V_{CC}  imes 0.3$	v
		$V_{CC}$ = 4.5 V to 5.5 V		$V_{CC}\!\times\!0.3$		$V_{CC}  imes 0.3$	
VI	Input voltage		0	5.5	0	5.5	V
.,		High or low state	0	Vcc	0	V <sub>CC</sub>	.,
Vo	Output voltage	3-state	0	5.5	0	5.5	V
		$V_{CC} = 2 V$		-50		-50	μA
		$V_{CC}$ = 2.3 V to 2.7 V		5 -2		-2	
I <sub>OH</sub>	High-level output current	$V_{CC}$ = 3 V to 3.6 V	0	-8		-8	mA
		$V_{CC}$ = 4.5 V to 5.5 V	Q	-16		-16	
		$V_{CC} = 2 V$		50		50	μA
		$V_{CC}$ = 2.3 V to 2.7 V		2		2	
I <sub>OL</sub>	Low-level output current	$V_{CC}$ = 3 V to 3.6 V		8		8	mA
		$V_{CC}$ = 4.5 V to 5.5 V		16		16	
		$V_{CC}$ = 2.3 V to 2.7 V		200		200	
Δt/Δv	Input transition rise or fall rate	$V_{CC}$ = 3 V to 3.6 V		100		100	ns/V
		$V_{CC}$ = 4.5 V to 5.5 V		20		20	
Τ <sub>Α</sub>	Operating free-air temperature		-55	125	-40	85	°C

NOTE 5: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

			SN54LV5734		SN74	ILV573A		
PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN TYP	MAX	MIN	ΤΥΡ Ν	IAX	UNIT
	I <sub>OH</sub> = –50 μA	2 V to 5.5 V	V <sub>CC</sub> -0.1		V <sub>CC</sub> -0.1			
N/	I <sub>OH</sub> = -2 mA	2.3 V	2		2			v
V <sub>OH</sub>	I <sub>OH</sub> = -8 mA	3 V	2.48		2.48			v
	I <sub>OH</sub> = -16 mA	4.5 V	3.8	b	3.8			
	I <sub>OL</sub> = 50 μA	2 V to 5.5 V	In.	0.1			0.1	
V	$I_{OL} = 2 \text{ mA}$	2.3 V	Ho	0.4			0.4	v
V <sub>OL</sub>	I <sub>OL</sub> = 8 mA	3 V	10	0.44		(	0.44	v
	I <sub>OL</sub> = 16 mA	4.5 V	ng	0.55		(	0.55	
l	$V_{I} = 5.5 V \text{ or GND}$	0 to 5.5 V	06	±1			±1	μA
I <sub>OZ</sub>	$V_O = V_{CC}$ or GND	5.5 V	4	±5			±5	μA
I <sub>CC</sub>	$V_{I} = V_{CC} \text{ or } GND, \qquad I_{O} = 0$	5.5 V		20			20	μA
I <sub>off</sub>	$V_{I}$ or $V_{O}$ = 0 to 5.5 V	0		5			5	μA
Ci	$V_{I} = V_{CC}$ or GND	3.3 V	1.8			1.8		pF

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#### timing requirements over recommended operating free-air temperature range, V<sub>CC</sub> = 2.5 V $\pm$ 0.2 V (unless otherwise noted) (see Figure 1)

					SN54LV573A		SN74LV573A		
	PARAMETER			MAX	MIN	МАХ	MIN	MAX	UNIT
tw	Pulse duration	LE high	6.5		6.5	12.0	6.5		ns
t <sub>su</sub>	Setup time	Data before LE $\downarrow$	5		5	JIP.	5		ns
t <sub>h</sub>	Hold time	Data after LE $\downarrow$	2		2		2		ns

#### timing requirements over recommended operating free-air temperature range, V<sub>CC</sub> = 3.3 V $\pm$ 0.3 V (unless otherwise noted) (see Figure 1)

	PARAMETER				SN54LV573A		SN74LV573A		LINUT
	PARAMETER			MAX	MIN	МАХ	MIN	MAX	UNIT
tw	Pulse duration	LE high	5		5	5.0	5		ns
t <sub>su</sub>	Setup time	Data before LE $\downarrow$	3.5		3.5	JIL	3.5		ns
t <sub>h</sub>	Hold time	Data after LE $\downarrow$	1.5		1,5		1.5		ns

#### timing requirements over recommended operating free-air temperature range, V<sub>CC</sub> = 5 V $\pm$ 0.5 V (unless otherwise noted) (see Figure 1)

		T <sub>A</sub> = 25°C		SN54LV573A		SN74LV573A			
	PARAMETER				MIN	MAX	MIN	MAX	UNIT
tw	Pulse duration	LE high	5		5	12.0	5		ns
t <sub>su</sub>	Setup time	Data before LE $\downarrow$	3.5		3.5	JIP .	3.5		ns
t <sub>h</sub>	Hold time	Data after LE $\downarrow$	1.5		1,5		1.5		ns

# switching characteristics over recommended operating free-air temperature range, $V_{CC}$ = 2.5 V $\pm$ 0.2 V (unless otherwise noted) (see Figure 1)

DADAMETED	FROM	то	LOAD	T,	₄ = 25°C	;	SN54L	/573A	SN74L	/573A	
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
•	D	Q			8.9*	15.8*	1*	18*	1	18	
t <sub>pd</sub>	LE	Q	0 15 55		9.6*	16.2*	1*	19*	1	19	ns
t <sub>en</sub>	ŌE	Q	C <sub>L</sub> = 15 pF		9.3*	16.2*	1*	19*	1	19	115
t <sub>dis</sub>	ŌĒ	Q			6.7*	12.6*	1*	15*	1	15	
	D	Q			10.9	18.7	T.	21	1	21	
t <sub>pd</sub>	LE	Q			11.6	19.1	200	23	1	23	
t <sub>en</sub>	ŌE	Q	C <sub>L</sub> = 50 pF		11.4	19	0 لار	22	1	22	ns
t <sub>dis</sub>	ŌĒ	Q			8.6	17.3	1	19	1	19	
t <sub>sk(o)</sub>						2				2	

\* On products compliant to MIL-PRF-38535, this parameter is not production tested.



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#### switching characteristics over recommended operating free-air temperature range, $V_{CC}$ = 3.3 V ± 0.3 V (unless otherwise noted) (see Figure 1)

	FROM	то	LOAD	Т	₄ = 25°C	;	SN54L	V573A	SN74L	/573A	
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	ТҮР	MAX	MIN	MAX	MIN	MAX	UNIT
	D	Q			6.2*	11*	1*	13*	1	13	
t <sub>pd</sub>	LE	Q	0 15 -5		6.8*	11.9*	1*	14*	1	14	ns
t <sub>en</sub>	ŌĒ	Q	C <sub>L</sub> = 15 pF		6.6*	11.5*	1*	13.5*	1	13.5	115
t <sub>dis</sub>	ŌĒ	Q			4.9*	11*	1*	13*	1	13	
	D	Q			7.7	14.5	T.	16.5	1	16.5	
t <sub>pd</sub>	LE	Q			8.2	15.4	50	17.5	1	17.5	
t <sub>en</sub>	ŌE	Q	C <sub>L</sub> = 50 pF		8	15	0 K	17	1	17	ns
t <sub>dis</sub>	ŌĒ	Q	[		6.2	14.5	1	16.5	1	16.5	
t <sub>sk(o)</sub>						1.5				1.5	

\* On products compliant to MIL-PRF-38535, this parameter is not production tested.

# switching characteristics over recommended operating free-air temperature range, $V_{CC}$ = 5 V $\pm$ 0.5 V (unless otherwise noted) (see Figure 1)

	FROM	то	LOAD	Т	₄ = 25°C	;	SN54L	V573A	SN74L	/573A	
PARAMETER	(INPUT)	(OUTPUT) CAPA	CAPACITANCE	MIN	ТҮР	MAX	MIN	MAX	MIN	MAX	UNIT
	D	Q			4.3*	6.8*	1*	8*	1	8	
t <sub>pd</sub>	LE	Q	0 – 15 pF		4.7*	7.7*	1*	9*	1	9	ns
t <sub>en</sub>	ŌĒ	Q	C <sub>L</sub> = 15 pF		4.7*	7.7*	1*	9*	1	9	115
t <sub>dis</sub>	ŌĒ	Q			3.5*	7.7*	1*	9*	1	9	
	D	Q			5.3	8.8	T.	10	1	10	
t <sub>pd</sub>	LE	Q			5.7	9.7	20	11	1	11	
t <sub>en</sub>	ŌE	Q	C <sub>L</sub> = 50 pF		5.7	9.7	Q 1	11	1	11	ns
t <sub>dis</sub>	ŌĒ	Q			4.2	9.7	1	11	1	11	
t <sub>sk(o)</sub>						1				1	

\* On products compliant to MIL-PRF-38535, this parameter is not production tested.

## noise characteristics, V<sub>CC</sub> = 3.3 V, C<sub>L</sub> = 50 pF, T<sub>A</sub> = 25°C (see Note 6)

		SN	UNIT		
	PARAMETER	MIN	ТҮР	MAX	UNIT
V <sub>OL(P)</sub>	Quiet output, maximum dynamic V <sub>OL</sub>		0.6	0.8	V
V <sub>OL(V)</sub>	Quiet output, minimum dynamic V <sub>OL</sub>		-0.5	-0.8	V
V <sub>OH(V)</sub>	Quiet output, minimum dynamic V <sub>OH</sub>		2.9		V
V <sub>IH(D)</sub>	High-level dynamic input voltage	2.31			V
V <sub>IL(D)</sub>	Low-level dynamic input voltage			0.99	V

NOTE 6: Characteristics are for surface-mount packages only.



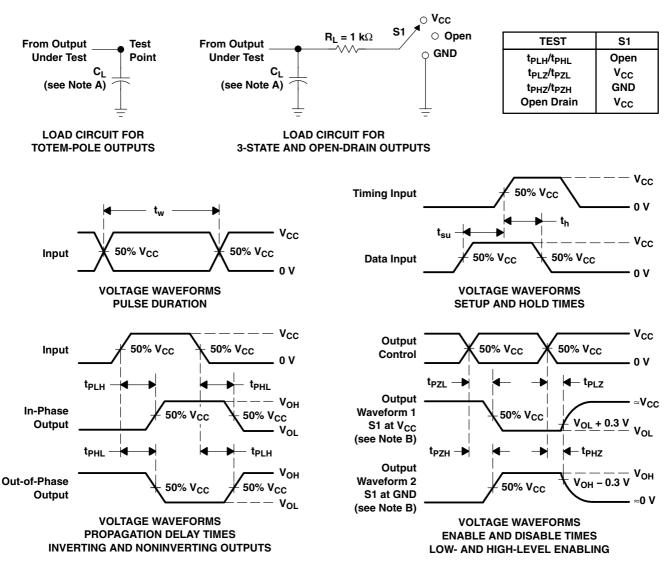
# SN54LV573A, SN74LV573A OCTAL TRANSPARENT D-TYPE LATCHES WITH 3-STATE OUTPUTS SCLS4111 – APRIL 1998 – REVISED APRIL 2005

## operating characteristics, $T_A = 25^{\circ}C$

	PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	TYP	UNIT		
C <sub>pd</sub>	Power dissipation capacitance	Outputs enabled			3.3 V	16	pF
			D to Q	C <sub>I</sub> = 50 pF, f = 10 MH	5 V	18	
			LE to Q	C <sub>L</sub> = 50 pF, f = 10 M⊦	2 3.3 V	18.2	
					5 V	21.3	



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#### PARAMETER MEASUREMENT INFORMATION

NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>r</sub>  $\leq$  3 ns, t<sub>f</sub>  $\leq$  3 ns.
- D. The outputs are measured one at a time, with one input transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G.  $t_{PHL}$  and  $t_{PLH}$  are the same as  $t_{pd}$ .
- H. All parameters and waveforms are not applicable to all devices.

#### Figure 1. Load Circuit and Voltage Waveforms





#### PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
							(6)				
SN74LV573ADBR	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV573A	Samples
SN74LV573ADBRG4	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV573A	Samples
SN74LV573ADGVR	ACTIVE	TVSOP	DGV	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV573A	Samples
SN74LV573ADW	ACTIVE	SOIC	DW	20	25	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV573A	Samples
SN74LV573ADWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV573A	Samples
SN74LV573ANSR	ACTIVE	SO	NS	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	74LV573A	Samples
SN74LV573APW	ACTIVE	TSSOP	PW	20	70	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV573A	Samples
SN74LV573APWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV573A	Samples
SN74LV573APWRG4	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV573A	Samples
SN74LV573APWT	ACTIVE	TSSOP	PW	20	250	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV573A	Samples
SN74LV573ARGYR	ACTIVE	VQFN	RGY	20	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	LV573A	Samples
SN74LV573ARGYRG4	ACTIVE	VQFN	RGY	20	3000	RoHS & Green	NIPDAU	Level-2-260C-1 YEAR	-40 to 85	LV573A	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <= 1000ppm threshold. Antimony trioxide based flame retardants must also meet the <= 1000ppm threshold requirement.



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## PACKAGE OPTION ADDENDUM

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

<sup>(6)</sup> Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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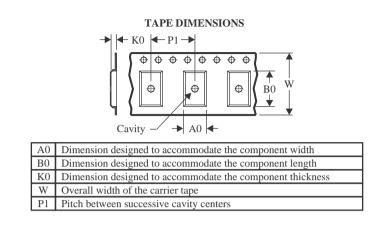


Texas

STRUMENTS

#### TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LV573ADBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74LV573ADGVR	TVSOP	DGV	20	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LV573ADWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74LV573ANSR	SO	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74LV573APWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74LV573APWT	TSSOP	PW	20	250	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74LV573ARGYR	VQFN	RGY	20	3000	330.0	12.4	3.8	4.8	1.6	8.0	12.0	Q1



www.ti.com

## PACKAGE MATERIALS INFORMATION

17-Jun-2022



		·,					
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LV573ADBR	SSOP	DB	20	2000	356.0	356.0	35.0
SN74LV573ADGVR	TVSOP	DGV	20	2000	356.0	356.0	35.0
SN74LV573ADWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74LV573ANSR	SO	NS	20	2000	367.0	367.0	45.0
SN74LV573APWR	TSSOP	PW	20	2000	356.0	356.0	35.0
SN74LV573APWT	TSSOP	PW	20	250	356.0	356.0	35.0
SN74LV573ARGYR	VQFN	RGY	20	3000	356.0	356.0	35.0

### TEXAS INSTRUMENTS

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### TUBE



### - B - Alignment groove width

\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
SN74LV573ADW	DW	SOIC	20	25	507	12.83	5080	6.6
SN74LV573APW	PW	TSSOP	20	70	530	10.2	3600	3.5

# **PW0020A**



## **PACKAGE OUTLINE**

## TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



## PW0020A

# **EXAMPLE BOARD LAYOUT**

## TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



## PW0020A

# **EXAMPLE STENCIL DESIGN**

## TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



## LAND PATTERN DATA



NOTES: Α. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
  C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



# **DB0020A**



# **PACKAGE OUTLINE**

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.



# DB0020A

# **EXAMPLE BOARD LAYOUT**

## SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



# DB0020A

# **EXAMPLE STENCIL DESIGN**

## SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



#### MECHANICAL DATA

#### PLASTIC SMALL-OUTLINE PACKAGE

#### 0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 $\bigcirc$ Gage Plane ₽ 0,25 7 1 1,05 0,55 0°-10° Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS \*\* 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G\*\*)

**14-PINS SHOWN** 

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



## **MECHANICAL DATA**

PLASTIC SMALL-OUTLINE

MPDS006C - FEBRUARY 1996 - REVISED AUGUST 2000

#### DGV (R-PDSO-G\*\*)

24 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
- D. Falls within JEDEC: 24/48 Pins MO-153

14/16/20/56 Pins – MO-194



## **GENERIC PACKAGE VIEW**

## VQFN - 1 mm max height

PLASTIC QUAD FGLATPACK - NO LEAD

3.5 x 4.5, 0.5 mm pitch

**RGY 20** 

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





4225264/A

# **RGY0020A**



# **PACKAGE OUTLINE**

### VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.
- 3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.



# **RGY0020A**

# **EXAMPLE BOARD LAYOUT**

## VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



# **RGY0020A**

# **EXAMPLE STENCIL DESIGN**

## VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



# **DW0020A**



## **PACKAGE OUTLINE**

### SOIC - 2.65 mm max height

SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



# DW0020A

# **EXAMPLE BOARD LAYOUT**

## SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



## DW0020A

# **EXAMPLE STENCIL DESIGN**

## SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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